

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

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Title of Invention

ULTRA-THIN SOI MOSFET METHOD AND STRUCTURE

Application Number :

Confirmation Number:

First Named Applicant: Louis Hsu

Attorney Docket Number: FIS920030348US1

Art Unit:

Examiner:

Search string: (6395589 or 6060749 or 4830975 or 6555880 or 6506649).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	6395589	2002-05-28	Yu			
	2	6060749	2000-05-09	Wu			
	3	4830975	1989-05-16	Bovaird, et al.			
	4	6555880	2003-04-29	Cabral, Jr., et al.			
	5	6506649	2003-01-14	Fung, et al.			

Signature

Examiner Name	Date